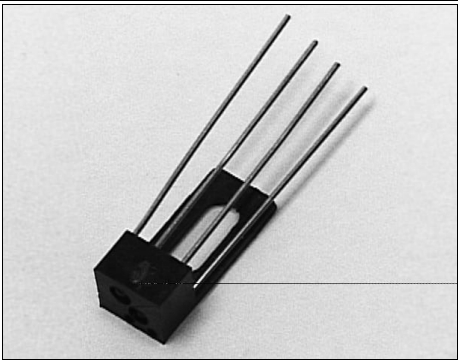


HOA2498

Reflective Sensor

FEATURES

- Choice of phototransistor or photodarlington output
- Focused for maximum response
- Wide operating temperature range (- 55°C to +100°C)



INFRA-64.TIF

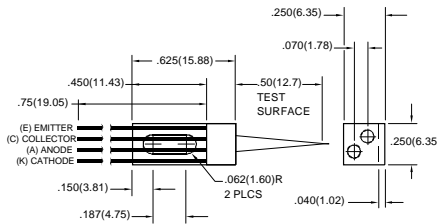
DESCRIPTION

The HOA2498 series consists of an infrared emitting diode and an NPN silicon phototransistor (HOA2498- 001, - 002) or photodarlington (HOA2498- 003), encased side- by- side on converging optical axes in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA2498 series employs metal can packaged components. For additional component information see SE1450, SD1440, and SD1410.

Housing material is polyester. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

Tolerance	3 plc decimals	±0.010(0.25)
	2 plc decimals	±0.020(0.51)



DIM_039.6s4

HOA2498

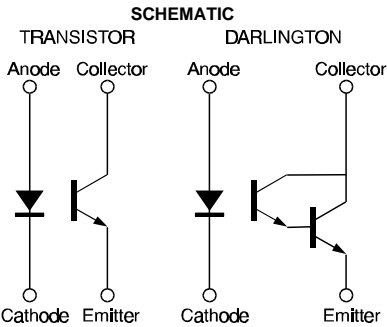
Reflective Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)							
PARAMETER		SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER							
Forward Voltage		V _F			1.6	V	I _F =20 mA
Reverse Leakage Current		I _R			10	μA	V _R =3 V
DETECTOR							
Collector-Emitter Breakdown Voltage HOA2498-001, -002 HOA2498-003		V _{(BR)CEO}		30 15		V	I _C =100 μA
Emitter-Collector Breakdown Voltage		V _{(BR)ECO}	5.0			V	I _E =100 μA
Collector Dark Current HOA2498-001, -002 HOA2498-003		I _{CEO}			100 250	nA	V _{CE} =10 V I _F =0
COUPLED CHARACTERISTICS							
On-State Collector Current HOA2498-001 HOA2498-002 HOA2498-003		I _{C(ON)}		0.04 0.16 2.0		mA	V _{CE} =5 V I _F =30 mA (1)
Collector-Emitter Saturation Voltage HOA2498-001 HOA2498-002 HOA2498-003		V _{CE(SAT)}			0.4 0.4 1.1	V	I _F =30 mA (1) I _C =5 μA I _C =20 μA I _C =250 μA
Rise And Fall Time HOA2498-001, -002 HOA2498-003		t _r , t _f		15 75		μs	V _{CC} =5 V, I _C =1 mA R _L =1000 Ω R _L =100 Ω

Notes
1. Test surface is a front surface mirror (polished aluminum, 85% reflectance) located 0.50 in.(12.7 mm) from the front surface of the device.

ABSOLUTE MAXIMUM RATINGS
(25°C Free-Air Temperature unless otherwise noted)
Operating Temperature Range -55°C to 100°C
Storage Temperature Range -55°C to 125°C
Soldering Temperature (10 sec) 260°C

IR EMITTER		
Power Dissipation	75 mW (1)	
Reverse Voltage	3 V	
Continuous Forward Current	50 mA	
DETECTOR		
Collector-Emitter Voltage	TRANS. 30 V	DARLINGTON 15 V
Emitter-Collector Voltage	5 V	5 V
Power Dissipation	75 mW (1)	75 mW (1)
Collector DC Current	30 mA	30 mA



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

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HOA2498

Reflective Sensor

Fig. 1 IRED Forward Bias Characteristics

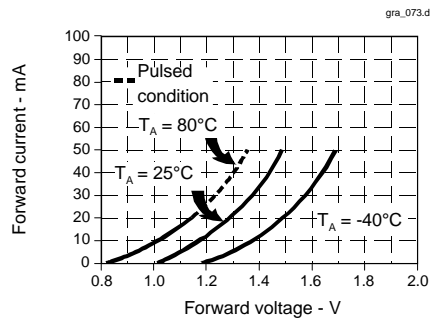


Fig. 2 Non-Saturated Switching Time vs Load Resistance

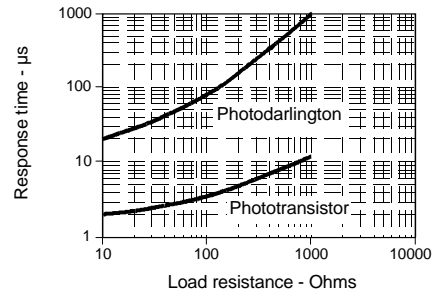


Fig. 3 Dark Current vs Temperature

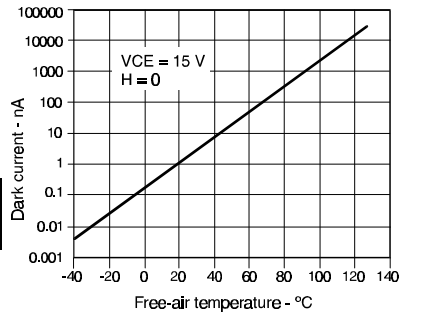


Fig. 4 Collector Current vs Ambient Temperature

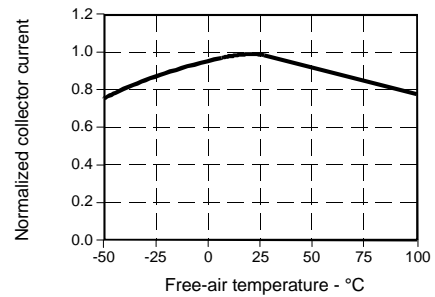


Fig. 5 Collector Current vs Distance to Reflective Surface

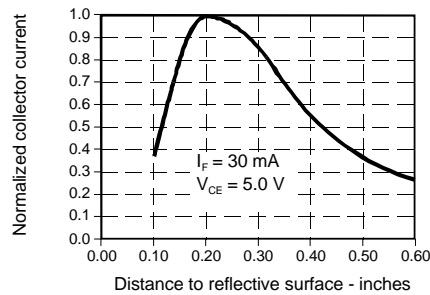
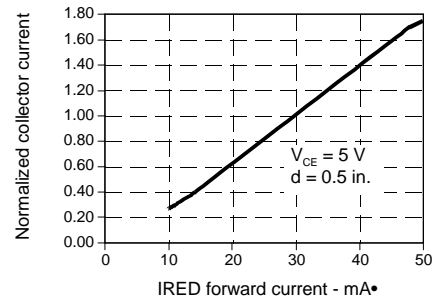


Fig. 6 Collector Current vs IRED Forward Current



All Performance Curves Show Typical Values

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